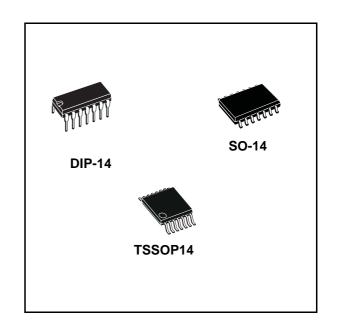


# M74HC14

## Hex Schmitt inverter

### Features

- High speed: t<sub>PD</sub> =12 ns (typ.) at V<sub>CC</sub> = 6 V
- Low power dissipation:
   I<sub>CC</sub> = 1 μA (max.) at T<sub>A</sub> = 25 °C
- High noise immunity: V<sub>H</sub> = 1.2 V (typ.) at V<sub>CC</sub> = 6 V
- Symmetrical output impedance: |I<sub>OH</sub>| = I<sub>OL</sub> = 4 mA (min.)
- Balanced propagation delays: t<sub>PLH</sub> ≅ t<sub>PHL</sub>
- Wide operating voltage range:
   V<sub>CC</sub> (opr) = 2 to 6 V
- Pin and function compatible with 74 series 14



### Description

The M74HC14 is a high speed CMOS hex Schmitt inverter fabricated with silicon gate  $C^2$ MOS technology. Pin configuration and functions are the same as those of the M74HC04 but all the inputs have 20% V<sub>CC</sub> hysteresis level.

This, together with its Schmitt trigger function, allows the device to be used on line receivers with slow rise/fall input signals.

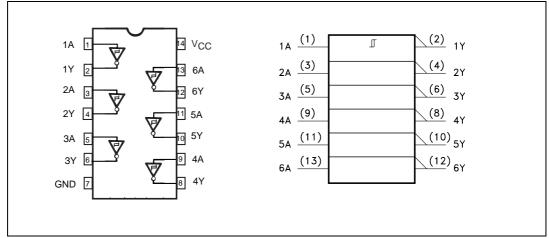
All inputs are equipped with protection circuits against static discharge and transient excess voltage.

Order code	Package	Packaging
M74HC14B1R	DIP-14	Tube
M74HC14RM13TR	SO-14	Tape and reel
M74HC14TTR	TSSOP14	Tape and reel

### Table 1. Device summary

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# 1 Pin connection and IEC logic symbols

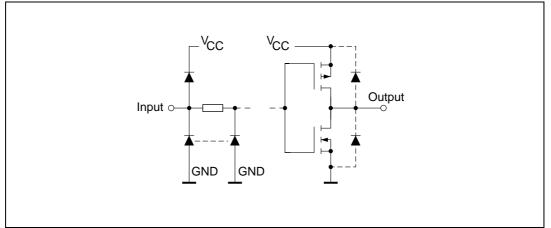


### Figure 1. Pin connections and IEC logic symbols

### Table 2.Pin description

Pin number	Symbol	Name and function
1, 3, 5, 9, 11, 13	1A to 6A	Data inputs
2, 4, 6, 8, 10, 12	1Y to 6Y	Data outputs
7	GND	Ground (0 V)
14	V <sub>CC</sub>	Positive supply voltage

### Figure 2. Input and output equivalent circuit



#### Table 3. Truth table

A	Y
L	н
н	L

## 2 Maximum rating

Stressing the device above the rating listed in the "Absolute maximum ratings" table may cause permanent damage to the device. These are stress ratings only, and operation of the device at these or any other conditions above those indicated in the operating sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Refer also to the STMicroelectronics SURE Program and other relevant quality documents.

Symbol	Parameter	Value	Unit			
V <sub>CC</sub>	Supply voltage	-0.5 to +7	V			
VI	DC input voltage	-0.5 to V <sub>CC</sub> + 0.5				
Vo	DC output voltage	-0.5 to V <sub>CC</sub> + 0.5	V			
I <sub>IK</sub>	DC input diode current	±20	mA			
Ι <sub>ΟΚ</sub>	DC output diode current	±20	mA			
Ι <sub>Ο</sub>	DC output current	±25	mA			
I <sub>CC</sub> or I <sub>GND</sub>	DC V <sub>CC</sub> or Ground current	±50	mA			
PD	Power dissipation	500 <sup>(1)</sup>	mW			
T <sub>stg</sub>	Storage temperature	-65 to +150	°C			
ΤL	Lead temperature (10 sec)	300	°C			

Table 4. Absolute maximum ratings

1. 500 mW at 65  $^{\circ}$  C; derate to 300 mW by 10 mW/  $^{\circ}$  C from 65  $^{\circ}$  C to 85  $^{\circ}$  C

### 2.1 Recommended operating conditions

#### Table 5. Recommended operating conditions

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	Supply voltage	2 to 6	V
VI	Input voltage	0 to V <sub>CC</sub>	V
Vo	Output voltage	0 to V <sub>CC</sub>	V
T <sub>op</sub>	Operating temperature	-55 to 125	°C



# 3 Electrical characteristics

Table 6.	DC specific										
		Те	st condition	Value							
Symbol	Parameter	V <sub>CC</sub> (V)		т,	T <sub>A</sub> = 25°C			°C	-55 to 125°C		Unit
		(•)		Min	Тур	Max	Min	Max	Min	Max	
		2.0		1.0	1.28	1.5	1.0	1.5	1.0	1.5	
V <sub>t+</sub>	V <sub>t+</sub> High level input voltage	4.5		2.3	2.8	3.15	2.3	3.15	2.3	3.15	V
		6.0		3.0	3.7	4.2	3.0	4.2	3.0	4.2	
		2.0		0.3	0.74	0.9	0.3	0.9	0.3	0.9	
V <sub>t</sub> -	Low level input voltage	4.5		1.13	1.8	2.0	1.13	2.0	1.13	2.0	V
	Volkago	6.0		1.5	2.4	2.6	1.5	2.6	1.5	2.6	
	2.0		0.3	0.54	1.0	0.3	1.0	0.3	1.0		
$V_{H}$	V <sub>H</sub> Hysteresis voltage	4.5		0.6	1.0	1.4	0.6	1.4	0.6	1.4	V
voltage	. en age	6.0		0.8	1.3	1.4	0.8	1.7	0.8	1.7	
		2.0	I <sub>O</sub> = -20 μA	1.9	2.0		1.9		1.9		
		4.5	I <sub>O</sub> = -20 μA	4.4	4.5		4.4		4.4		
V <sub>OH</sub>	High level output voltage	6.0	I <sub>O</sub> = -20 μA	5.9	6.0		5.9		5.9		V
	o alpar ronago	4.5	l <sub>O</sub> = -4.0 mA	4.18	4.31		4.13		4.10		
		6.0	l <sub>O</sub> = -5.2 mA	5.68	5.8		5.63		5.60		
		2.0	I <sub>O</sub> = -20 μA		0.0	0.1		0.1		0.1	
		4.5	I <sub>O</sub> = -20 μA		0.0	0.1		0.1		0.1	
V <sub>OL</sub>	Low level output voltage	6.0	I <sub>O</sub> = -20 μA		0.0	0.1		0.1		0.1	V
		4.5	l <sub>O</sub> = -4.0 mA		0.17	0.26		0.33		0.40	
		6.0	l <sub>O</sub> = -5.2 mA		0.18	0.26		0.33		0.40	
I	Input leakage current	6.0	V <sub>I</sub> = V <sub>CC</sub> or GND			±0.1		±1		±1	μA
I <sub>CC</sub>	Quiescent supply current	6.0	V <sub>I</sub> = V <sub>CC</sub> or GND			1		10		20	μA

### Table 6. DC specifications



		Test condition		Value							
Symbol Parameter	V <sub>CC</sub> (V)		T <sub>A</sub> = 25 °C			-40 to 85 °C		-55 to 125 °C		Unit	
		(V)	Min	Тур	Max	Min	Max	Min	Max		
		2.0			30	75		95		110	
t <sub>TLH</sub> t <sub>THL</sub>	Output transition time	4.5			8	15		19		22	ns
		6.0			7	13		16		19	
		2.0			42	125		155		190	
Propagation delay	4.5			14	25		31		38	ns	
		6.0			12	21		16		32	

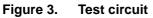
### **Table 7.** AC electrical characteristics ( $C_L = 50 \text{ pF}$ , Input $t_r = t_f = 6 \text{ ns}$ )

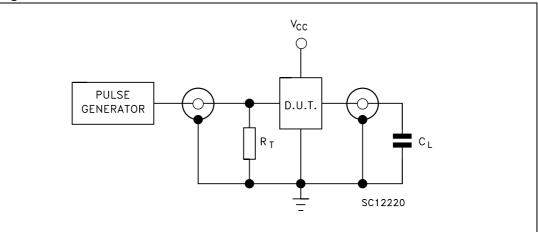
### Table 8. Capacitive characteristics

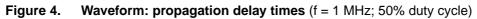
		Test condition		Value							
Symbol	ool Parameter V <sub>CC</sub> (V)				T <sub>A</sub> = 25°C		-40 to 85°C		-55 to 125°C		Unit
			Min	Тур	Max	Min	Max	Min	Max		
C <sub>IN</sub>	Input capacitance	5.0			5	10		10		10	pF
C <sub>PD</sub>	Power dissipation capacitance <sup>(1)</sup>	5.0	f <sub>IN</sub> = 10 MHz		28						pF

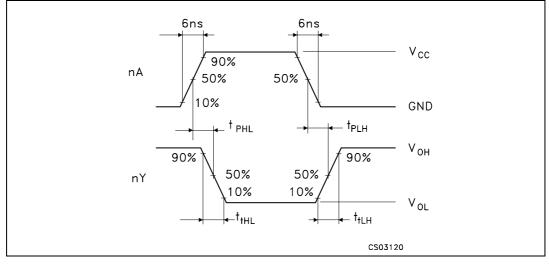
1.  $C_{PD}$  is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to test circuit). Average operating current can be obtained by the following equation:  $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/6(per gate).$ 

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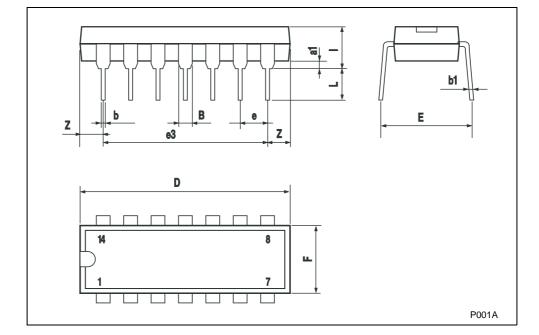


## 4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK<sup>®</sup> packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

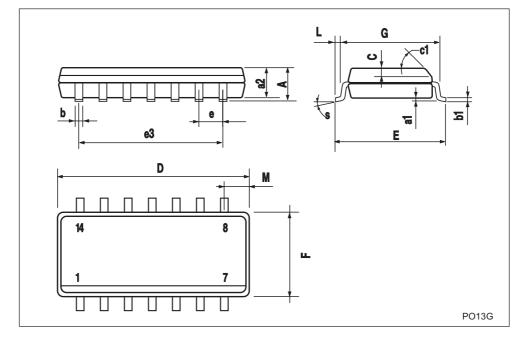


	Plastic DIP-14 MECHANICAL DATA									
DIM		mm.		inch						
DIM.	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.				
a1	0.51			0.020						
В	1.39		1.65	0.055		0.065				
b		0.5			0.020					
b1		0.25			0.010					
D			20			0.787				
E		8.5			0.335					
е		2.54			0.100					
e3		15.24			0.600					
F			7.1			0.280				
I			5.1			0.201				
L		3.3			0.130					
Z	1.27		2.54	0.050		0.100				





	SO-14 MECHANICAL DATA								
DIM.		mm.			inch				
DIN.	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.			
А			1.75			0.068			
a1	0.1		0.2	0.003		0.007			
a2			1.65			0.064			
b	0.35		0.46	0.013		0.018			
b1	0.19		0.25	0.007		0.010			
С		0.5			0.019				
c1			45°	(typ.)	1				
D	8.55		8.75	0.336		0.344			
E	5.8		6.2	0.228		0.244			
е		1.27			0.050				
e3		7.62			0.300				
F	3.8		4.0	0.149		0.157			
G	4.6		5.3	0.181		0.208			
L	0.5		1.27	0.019		0.050			
М			0.68			0.026			
S		1	8° (I	max.)					

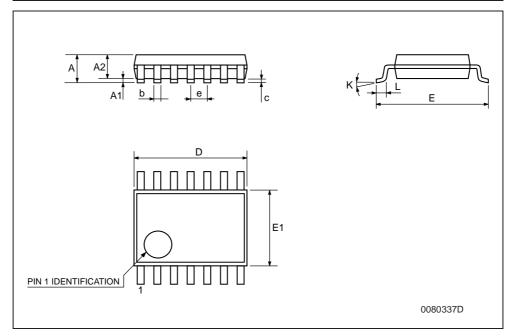


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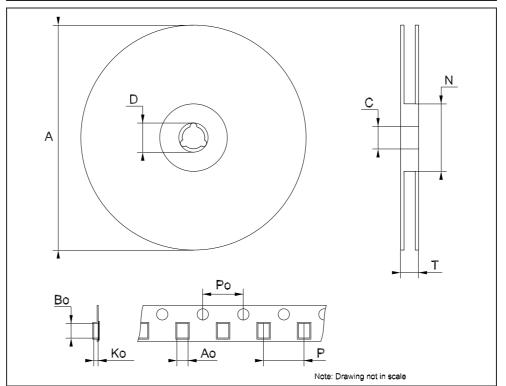
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	TSSOP14 MECHANICAL DATA									
DIM.		mm.			inch					
DIM.	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.				
А			1.2			0.047				
A1	0.05		0.15	0.002	0.004	0.006				
A2	0.8	1	1.05	0.031	0.039	0.041				
b	0.19		0.30	0.007		0.012				
С	0.09		0.20	0.004		0.0089				
D	4.9	5	5.1	0.193	0.197	0.201				
Е	6.2	6.4	6.6	0.244	0.252	0.260				
E1	4.3	4.4	4.48	0.169	0.173	0.176				
е		0.65 BSC			0.0256 BSC					
К	0°		8°	0°		8°				
L	0.45	0.60	0.75	0.018	0.024	0.030				





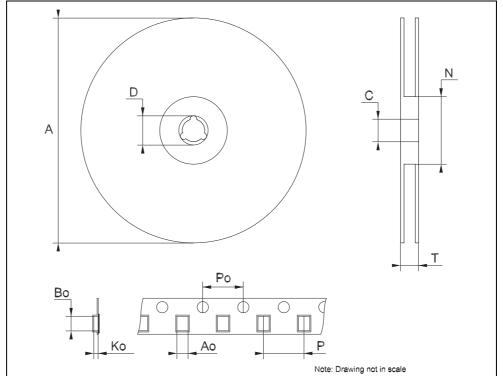
	Tape & Reel SO-14 MECHANICAL DATA									
DIM.		mm.		İ	inch					
DIN.	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.				
А			330			12.992				
С	12.8		13.2	0.504		0.519				
D	20.2			0.795						
Ν	60			2.362						
Т			22.4			0.882				
Ao	6.4		6.6	0.252		0.260				
Во	9		9.2	0.354		0.362				
Ko	2.1		2.3	0.082		0.090				
Po	3.9		4.1	0.153		0.161				
Р	7.9		8.1	0.311		0.319				





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DIM.	mm.			inch		
	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.
А			330			12.992
С	12.8		13.2	0.504		0.519
D	20.2			0.795		
Ν	60			2.362		
т			22.4			0.882
Ao	6.7		6.9	0.264		0.272
Во	5.3		5.5	0.209		0.217
Ko	1.6		1.8	0.063		0.071
Po	3.9		4.1	0.153		0.161
Р	7.9		8.1	0.311		0.319





# 5 Revision history

Table 9. Docu	ment revision	history
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Date	Revision	Changes	
01-Jul-2001	1	Initial release.	
23-May-2008	2	Document converted and restructured to new template. Removed: M74HC14M1R order code. Added: tape and reel specifications for SO-14 and TSSOP14 packages.	



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